

dielectric substrate which connects two conductor parallel plates at the top and bottom of the substrate. Therefore, a synthetic rectangular waveguide filled with dielectric material is made in planar form. The diameter of cylindrical posts is d and they are separated in transverses and axial plane by S and W respectively.

Experimental and numerical methods reveal that the propagation characteristics of dominant mode of the SIW structures are equivalent to those of an equivalent metallic rectangular waveguide with the effective width of W_{eff} . So, it is assumed that the effective width is generally related to the geometrical parameters. Thus, two expressions using unknown coefficients are defined for evaluating the effective width of SIW structures [7-10].

$$W_{eff} = \gamma_1 W + \gamma_2 \frac{d}{S} W + \gamma_3 \frac{d^2}{S} + \gamma_4 \frac{d^2}{W}, \quad (2)$$

$$W_{eff} = \sigma_1 W + \sigma_2 S + \sigma_3 d + \sigma_4 \frac{d^2}{S} + \sigma_5 \frac{d^2}{W}. \quad (3)$$

Unknown coefficients can be calculated using LSM procedure. Table 1 shows the calculated unknown coefficients.

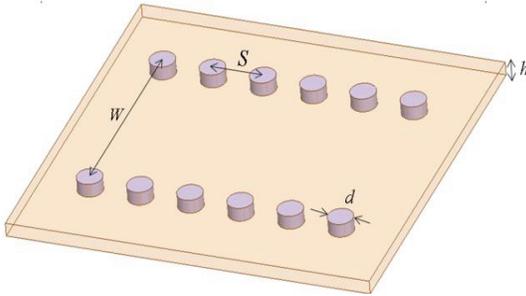


Fig. 1. Geometry of the SIW structure.

Table 1: Calculated unknown coefficients using LSM

i	γ_i	σ_i
1	1.3	1.103
2	-1.026	0.552
3	7.957	-3.222
4	-22.015	4.553
5	0	-10.974
$E(\text{error})$	2.9×10^{-4}	2.3×10^{-4}

IV. RESULTS VERIFICATION

To verify the accuracy of the proposed method, four examples are presented.

A. Example I

In the first one, a specific SIW structure with geometrical parameters of $W=3.97$ mm, $d=0.635$ mm,

$S=1.016$ mm and relative permittivity of 9.9 is considered. Numerical results for cutoff frequency of TE_{10} mode of this structure is shown in Fig. 2. It can be seen that a very good agreement is obtained between the measured results and those obtained by the proposed W_{eff} using Equation 3. A small deviation between results can be seen, but still proposed W_{eff} method using Equation 2 in this paper accurately predicts propagation constant of the structure.

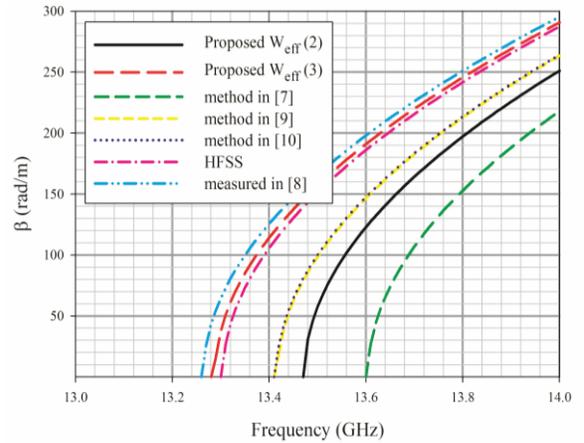


Fig. 2. Propagation constant of TE_{10} mode versus frequency for SIW structure I.

B. Example II

In the second example, another specific SIW structure with geometrical parameters of $W=7.2$ mm, $S=2$ mm and relative permittivity of 2.33 is considered. Cutoff frequency of TE_{10} mode of this SIW structure versus via diameter d , is shown in Fig. 3. These results indicate that both proposed W_{eff} using Equations 2 and 3 predicts same dispersion characteristics and agree well with other published methods.

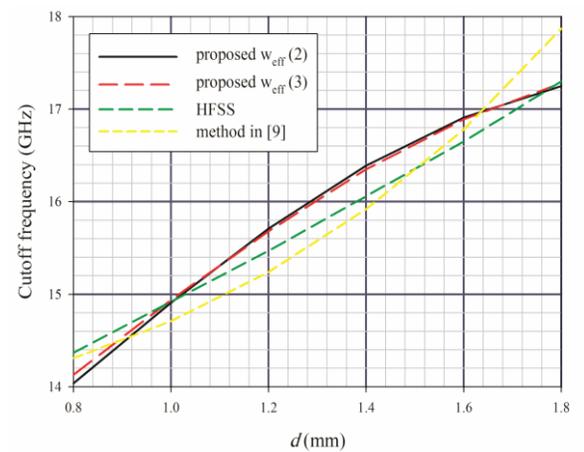


Fig. 3. Cutoff frequency of TE_{10} mode versus via diameter d for the 2^d SIW structure.

C. Example III

A SIW structure with parameters $W=5.25$ mm, $d=0.8$ mm, $S=1.5$ mm and $\epsilon_r=2.2$ is considered in the third example. Numerical results of the propagation constant of the mentioned structure at TE₁₀ mode versus frequency of the presented method in this paper are shown in Fig. 4. It shows that our results and measured results in [10] agree very well.

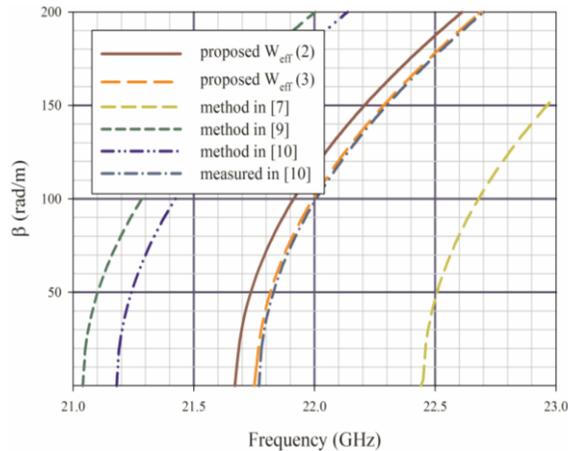


Fig. 4. Propagation constant of TE₁₀ mode versus the 3rd SIW structure.

D. Example IV

In the fourth example, a specific SIW structure with geometrical parameters of $S=1.5$ mm and relative permittivity of 2.2 is considered. Numerical results of cutoff frequency for this structure at TE₁₀ mode are shown in Fig. 5 versus W , width of the structure for different values of via diameter d . It can be concluded that the results of the proposed method in this paper agree very well with those presented in [9].

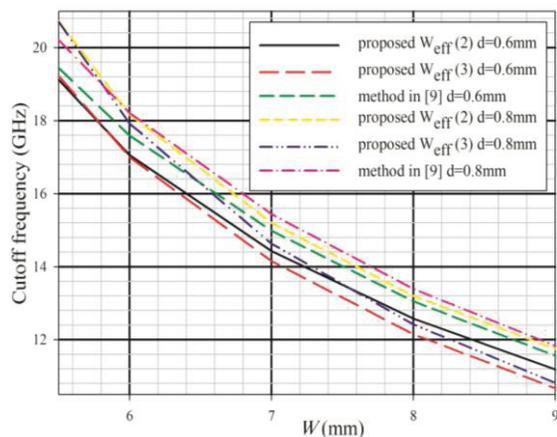


Fig. 5. Cutoff frequency of TE₁₀ mode versus W for different values of d for 4th SIW structure.

V. CONCLUSION

In this paper, an accurate closed-form expression is introduced using least squares method (LSM) to calculate the effective width of the substrate integrated waveguide (SIW). The effects of geometrical parameters of the structure on propagation constant and cutoff frequency are investigated for four specific SIW structures. The results for propagation constant and cutoff frequency of the dominant mode of the SIW structures are in a very good agreement with other reported simulation and measured results. The proposed method using LSM accurately predicts the dispersion characteristics of the SIW for a wide range of structure parameters. Therefore, it could be used for designing wide variety of SIW structure.

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